Functional Safety Information CD74HCT4067-Q1 Functional Safety FIT Rate, FMD and Pin FMA

TEXAS INSTRUMENTS

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1 Overview

This document contains information for the CD74HCT4067-Q1 (SOIC package) to aid in a functional safety system design. Information provided are:

- Functional safety failure in time (FIT) rates of the semiconductor component estimated by the application of industry reliability standards
- Component failure modes and their distribution (FMD) based on the primary function of the device
- Pin failure mode analysis (pin FMA)

Figure 1-1 shows the device functional block diagram for reference.

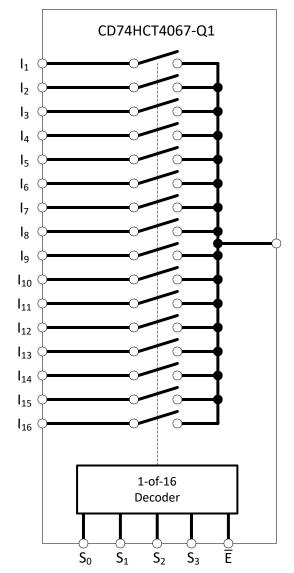


Figure 1-1. Functional Block Diagram

The CD74HCT4067-Q1 was developed using a quality-managed development process, but was not developed in accordance with the IEC 61508 or ISO 26262 standards.



2 Functional Safety Failure In Time (FIT) Rates

This section provides functional safety failure in time (FIT) rates for the SOIC package of the CD74HCT4067-Q1 based on two different industry-wide used reliability standards:

- Table 2-1 provides FIT rates based on IEC TR 62380 / ISO 26262 part 11
- Table 2-2 provides FIT rates based on the Siemens Norm SN 29500-2

Table 2-1. Component Failure Rates per IEC TR 62380 / ISO 26262 Part 11

| FIT IEC TR 62380 / ISO 26262 | FIT (Failures Per 10 ⁹ Hours) |
|------------------------------|--|
| Total component FIT rate | 15 |
| Die FIT rate | 5 |
| Package FIT rate | 10 |

The failure rate and mission profile information in Table 2-1 comes from the reliability data handbook IEC TR 62380 / ISO 26262 part 11:

- Mission profile: motor control from table 11
- Power dissipation: 141 mW
- Climate type: world-wide table 8
- Package factor (lambda 3): table 17b
- Substrate material: FR4
- EOS FIT rate assumed: 0 FIT

Table 2-2. Component Failure Rates per Siemens Norm SN 29500-2

| Table | Category | Reference FIT Rate | Reference Virtual T _J |
|-------|---|--------------------|----------------------------------|
| 5 | BICMOS ASICs Analog and Mixed =< 50V supply | 20 FIT | 55°C |

The reference FIT rate and reference virtual T_J (junction temperature) in Table 2-2 come from the Siemens Norm SN 29500-2 tables 1 through 5. Failure rates under operating conditions are calculated from the reference failure rate and virtual junction temperature using conversion information in SN 29500-2 section 4.



3 Failure Mode Distribution (FMD)

The failure mode distribution estimation for the CD74HCT4067-Q1 in Table 3-1 comes from the combination of common failure modes listed in standards such as IEC 61508 and ISO 26262, the ratio of sub-circuit function size and complexity, and from best engineering judgment.

The failure modes listed in this section reflect random failure events and do not include failures resulting from misuse or overstress.

| Die Failure Modes | Failure Mode Distribution (%) |
|---|-------------------------------|
| MUX no output (HIZ) | 35 |
| MUX channel stuck on | 10 |
| MUX channel stuck off | 10 |
| MUX functional out of specification voltage or timing | 45 |

Table 3-1. Die Failure Modes and Distribution



4 Pin Failure Mode Analysis (Pin FMA)

- Pin short-circuited to ground (see Table 4-2)
- Pin open-circuited (see Table 4-3)
- Pin short-circuited to an adjacent pin (see Table 4-4)
- Pin short-circuited to supply (see Table 4-5)

Table 4-2 through Table 4-5 also indicate how these pin conditions can affect the device as per the failure effects classification in Table 4-1.

| Table 4-1. | TI Classification | of Failure Effects |
|------------|--------------------------|--------------------|
|------------|--------------------------|--------------------|

| Class | Failure Effects | | |
|-------|---|--|--|
| A | Potential device damage that affects functionality | | |
| В | No device damage, but loss of functionality | | |
| С | No device damage, but performance degradation | | |
| D | No device damage, no impact to functionality or performance | | |

Figure 4-1 shows the CD74HCT4067-Q1 pin diagram for the SOIC package. For a detailed description of the device pins please refer to the *Pin Configuration and Functions* section in the CD74HCT4067-Q1 data sheet.

| COMMON I/O | 1 | 24 V _{CC} |
|---|----|--------------------|
| I7 | 2 | 23 I ₈ |
| I6 | 3 | 22 I ₉ |
| I5 | 4 | 21 I ₁₀ |
| I4 | 5 | 20 I ₁₁ |
| I3 | 6 | 19 I ₁₂ |
| I2 | 7 | 18 I ₁₃ |
| I1 | 8 | 17 I ₁₄ |
| I0 | 9 | 16 I ₁₅ |
| So | 10 | 15 E |
| I ₀ [S ₀ [S ₁ [GND [| | E <u>1</u> 3 |

Figure 4-1. Pin Diagram (SOIC) Package

| Pin Name | Pin No. | Description of Potential Failure Effect(s) | Failure Effect Class |
|------------|---------|---|----------------------------|
| COMMON I/O | 1 | Corruption of the signal passed onto the selected lx pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 17 | 2 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 16 | 3 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 15 | 4 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 14 | 5 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 13 | 6 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 12 | 7 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 11 | 8 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 10 | 9 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| S0 | 10 | Address stuck low. Cannot control switch states. | В |
| S1 | 11 | Address stuck low. Cannot control switch states. | В |
| GND | 12 | No effect, normal operation. | D |
| S3 | 13 | Address stuck low. Cannot control switch states. | А |
| S2 | 14 | Address stuck low. Cannot control switch states. | А |
| E/ | 15 | Enable stuck low. Can no longer disable the device without power down. | В |
| 115 | 16 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 114 | 17 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 113 | 18 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 112 | 19 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 111 | 20 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 110 | 21 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 19 | 22 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 18 | 23 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| VDD | 24 | Device is unpowered. Device is not functional. Observe that the absolute maximum ratings for all pins of the device are met; otherwise device damage may be possible. | А |

Table 4-2. Pin FMA for Device Pins Short-Circuited to Ground

| Pin Name | Pin No. | Description of Potential Failure Effect(s) | Failure Effect Class |
|------------|---------|---|----------------------------|
| COMMON I/O | 1 | Corruption of the signal passed onto the Ix pins | В |
| 17 | 2 | Corruption of the signal passed onto the COMMON I/O pin | В |
| 16 | 3 | Corruption of the signal passed onto the COMMON I/O pin | В |
| 15 | 4 | Corruption of the signal passed onto the COMMON I/O pin | В |
| 14 | 5 | Corruption of the signal passed onto the COMMON I/O pin | В |
| 13 | 6 | Corruption of the signal passed onto the COMMON I/O pin | В |
| 12 | 7 | Corruption of the signal passed onto the COMMON I/O pin | В |
| l1 | 8 | Corruption of the signal passed onto the COMMON I/O pin | В |
| 10 | 9 | Corruption of the signal passed onto the COMMON I/O pin | В |
| S0 | 10 | Control of the address pin is lost. Cannot control switch. | В |
| S1 | 11 | Control of the address pin is lost. Cannot control switch. | В |
| GND | 12 | Device unpowered. Device not functional. Observe that the absolute maximum ratings for all pins of the device are met, otherwise device damage is possible. | A |
| S3 | 13 | Control of the address pin is lost. Cannot control switch. | В |
| S2 | 14 | Control of the address pin is lost. Cannot control switch. | В |
| E/ | 15 | Loss of control of the E/ pin. Cannot control the device. | В |
| 115 | 16 | Corruption of the signal passed onto the COMMON I/O pin | В |
| 114 | 17 | Corruption of the signal passed onto the COMMON I/O pin | В |
| 113 | 18 | Corruption of the signal passed onto the COMMON I/O pin | В |
| l12 | 19 | Corruption of the signal passed onto the COMMON I/O pin | В |
| I11 | 20 | Corruption of the signal passed onto the COMMON I/O pin | В |
| I10 | 21 | Corruption of the signal passed onto the COMMON I/O pin | В |
| 19 | 22 | Corruption of the signal passed onto the COMMON I/O pin | В |
| 18 | 23 | Corruption of the signal passed onto the COMMON I/O pin | В |
| VDD | 24 | Device is unpowered. Device is not functional. | В |

Table 4-3. Pin FMA for Device Open-Circuited

| Pin Name | Pin No. | Shorted to | Description of Potential Failure Effect(s) | Failure Effect Class |
|------------|---------|------------|---|----------------------------|
| COMMON I/O | 1 | 17 | Possible corruption of the signal passed onto the IX and COMMON I/O pin. | В |
| 17 | 2 | 16 | Possible corruption of the signal passed onto the COMMON I/O pin. | В |
| 16 | 3 | 15 | Possible corruption of the signal passed onto the COMMON I/O pin. | В |
| 15 | 4 | 14 | Possible corruption of the signal passed onto the COMMON I/O pin. | В |
| 14 | 5 | 13 | Possible corruption of the signal passed onto the COMMON I/O pin. | В |
| 13 | 6 | 12 | Possible corruption of the signal passed onto the COMMON I/O pin. | В |
| 12 | 7 | l1 | Possible corruption of the signal passed onto the COMMON I/O pin. | В |
| l1 | 8 | 10 | Possible corruption of the signal passed onto the COMMON I/O pin. | В |
| 10 | 9 | S0 | Possible corruption of the signal passed onto the COMMON I/O pin. | В |
| S0 | 10 | S1 | Possible corruption of the signal passed onto the COMMON I/O pin. | В |
| S1 | 11 | GND | Control of the address pin is lost. Cannot control switch. | В |
| GND | 12 | S3 | Not considered, corner pin. | D |
| S3 | 13 | S2 | Control of the address pin is lost. Cannot control switch. | В |
| S2 | 14 | E/ | Control of the address and Enable pin is lost. Cannot control switch. | В |
| E/ | 15 | l15 | Control of the address pin is lost. Cannot control switch. | В |
| 115 | 16 | 114 | Possible corruption of the signal passed onto the COMMON I/O pin. | В |
| 114 | 17 | I13 | Possible corruption of the signal passed onto the COMMON I/O pin. | В |
| 113 | 18 | l12 | Possible corruption of the signal passed onto the COMMON I/O pin. | В |
| 112 | 19 | I11 | Possible corruption of the signal passed onto the COMMON I/O pin. | В |
| l11 | 20 | I10 | Possible corruption of the signal passed onto the COMMON I/O pin. | В |
| I10 | 21 | 19 | Possible corruption of the signal passed onto the COMMON I/O pin. | В |
| 19 | 22 | 18 | Possible corruption of the signal passed onto the COMMON I/O pin. | В |
| 18 | 23 | VCC | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| VCC | 24 | COMMON I/O | Not considered, corner pin. | D |

Table 4-4. Pin FMA for Device Pins Short-Circuited to Adjacent Pin

| Pin Name | Pin No. | Description of Potential Failure Effect(s) | Failure Effect Class |
|------------|---------|---|----------------------------|
| COMMON I/O | 1 | Corruption of the signal passed onto the Ix pins. If there is no limiting resistor in the switch path, then device damage is possible. | A |
| 17 | 2 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | A |
| 16 | 3 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 15 | 4 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 14 | 5 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | A |
| 13 | 6 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 12 | 7 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 11 | 8 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 10 | 9 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| S0 | 10 | Address stuck high. Cannot control switch. | В |
| S1 | 11 | Address stuck high. Cannot control switch. | В |
| GND | 12 | Device is unpowered. Device is not functional. Observe that the absolute maximum ratings for all pins of the device are met, otherwise device damage may be possible. | A |
| S3 | 13 | Address stuck high. Cannot control switch. | В |
| S2 | 14 | Address stuck high. Cannot control switch. | В |
| E/ | 15 | E/ stuck high. Can no longer disable the device | В |
| 115 | 16 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | A |
| 114 | 17 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 113 | 18 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 112 | 19 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | A |
| 111 | 20 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | A |
| 110 | 21 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | A |
| 19 | 22 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | А |
| 18 | 23 | Corruption of the signal passed onto the COMMON I/O pin. If there is no limiting resistor in the switch path, then device damage is possible. | A |
| VDD | 24 | No effect, normal operation. | D |

Table 4-5. Pin FMA for Device Pins Short-Circuited to VDD

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